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- EPIC[™] (Enhanced-Performance Implanted CMOS) Process
- Typical V_{OLP} (Output Ground Bounce)
 < 0.8 V at V_{CC}, T_A = 25°C
- Typical V_{OHV} (Output V_{OH} Undershoot)
 > 2 V at V_{CC}, T_A = 25°C
- Latch-Up Performance Exceeds 250 mA Per JESD 17
- ESD Protection Exceeds 200 V Per MIL-STD-883, Method 3015; Exceeds 200 V Using Machine Model (C = 200 pF, R = 0)
- Package Options Include Plastic Small-Outline (DW, NS), Shrink Small-Outline (DB), Thin Very Small-Outline (DGV), and Thin Shrink Small-Outline (PW) Packages, Ceramic Flat (W) Package, Chip Carriers (FK), and DIPs (J)

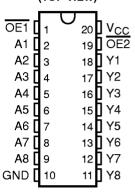
description

The 'LV541A devices are octal buffers/drivers designed for 2-V to 5.5-V V_{CC} operation.

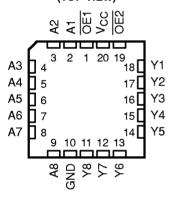
These devices are ideal for driving bus lines or buffer memory address registers. They feature inputs and outputs on opposite sides of the package to facilitate printed circuit board layout.

The 3-state control gate is a two-input AND gate with active-low inputs so that if either output-enable (OE1 or OE2) input is high, all corresponding outputs are in the high-impedance state. The outputs provide noninverted data when they are not in the high-impedance state.

SN54LV541A . . . J OR W PACKAGE SN74LV541A . . . DB, DGV, DW, NS, OR PW PACKAGE (TOP VIEW)



SN54LV541A . . . FK PACKAGE (TOP VIEW)



To ensure the high-impedance state during power up or power down, \overline{OE} should be tied to V_{CC} through a pullup resistor; the minimum value of the resistor is determined by the current-sinking capability of the driver.

The SN54LV541A is characterized for operation over the full military temperature range of –55°C to 125°C. The SN74LV541A is characterized for operation from –40°C to 85°C.

FUNCTION TABLE (each buffer/driver)

	INPUTS		
	INFUIS		OUTPUT
OE1	OE2	Α	Y
L	L	L	L
L	L	Н	Н
Н	Х	Χ	Z
×	Н	Χ	Z

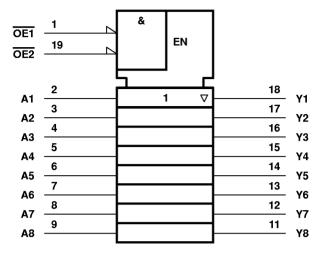


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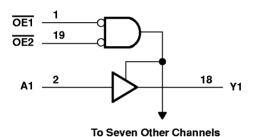


logic symbol†



[†]This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



absolute maximum ratings over operating free-air temperature range (unless otherwise noted)‡

Supply voltage range, V _{CC}		–0.5 V to 7 V
Input voltage range, V _I (see Note 1)		–0.5 V to 7 V
Output voltage range applied in the high or low	state, VO (see Notes 1 and 2)0.5 V t	to V_{CC} + 0.5 V
Output voltage range applied in high-impedance	e or power-off state, VO (see Note 1)	–0.5 V to 7 V
Input clamp current, I_{IK} ($V_I < 0$)		–20 mA
Output clamp current, I _{OK} (V _O < 0 or V _O > V _{CC}	;)	±50 mA
Continuous output current, $I_O(V_O = 0 \text{ to } V_{CC})$	• • • • • • • • • • • • • • • • • • • •	±35 mA
Continuous current through V _{CC} or GND		±70 mA
Package thermal impedance, θ _{JA} (see Note 3):	DB package	115°C/W
	DGV package	146°C/W
	DW package	97°C/W
	NS package	100°C/W
	PW package	128°C/W
Storage temperature range, T _{sto}		65°C to 150°C

[‡] Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

- 2. This value is limited to 7 V maximum.
- 3. The package thermal impedance is calculated in accordance with JESD 51.



NOTES: 1. The input and output voltage ratings may be exceeded if the input and output current ratings are observed.

recommended operating conditions (see Note 4)

			SN54L	SN54LV541A		SN74LV541A	
			MIN	MAX	MIN	MAX	UNIT
Vcc	Supply voltage		2	5.5	2	5.5	V
		V _{CC} = 2 V	1.5		1.5		
V	High lovel input veltage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	V _{CC} ×0.7		$V_{CC} \times 0.7$		\ ,
V_{IH}	High-level input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	V _{CC} ×0.7		$V_{CC} \times 0.7$		V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	V _{CC} ×0.7		V _{CC} ×0.7		
		V _{CC} = 2 V		0.5		0.5	
	Level by all input valtage	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		$V_{CC} \times 0.3$		$V_{CC} \times 0.3$	V
VIL	Low-level input voltage	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		$V_{CC} \times 0.3$		$V_{CC} \times 0.3$]
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		V _{CC} ×0.3		V _{CC} ×0.3	
VI	Input voltage		0	5.5	0	5.5	V
V/ -	Output voltage	High or low state	0	Vcc	0	Vcc	V
VO		3-state	0 %	5.5	0	5.5]
		V _{CC} = 2 V		– 50		-50	μΑ
1	High lovel output ourrent	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		– 2		-2	
IOH	High-level output current	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$	7	-8		-8	mA
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		-16		-16	
		V _{CC} = 2 V		50		50	μΑ
1	I I	$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$		2		2	
lOL	Low-level output current	$V_{CC} = 3 \text{ V to } 3.6 \text{ V}$		8		8	mA
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$		16		16	
		$V_{CC} = 2.3 \text{ V to } 2.7 \text{ V}$	0	200	0	200	
Δt/Δν	Input transition rise or fall rate	V _{CC} = 3 V to 3.6 V	0	100	0	100	ns/V
		$V_{CC} = 4.5 \text{ V to } 5.5 \text{ V}$	0	20	0	20	
TA	Operating free-air temperature		-55	125	-40	85	°C

NOTE 4: All unused inputs of the device must be held at VCC or GND to ensure proper device operation. Refer to the TI application report, Implications of Slow or Floating CMOS Inputs, literature number SCBA004.

electrical characteristics over recommended operating free-air temperature range (unless otherwise noted)

DADAMETED	TEST COMPITIONS	.,	SN54LV541A	SN74LV541A	LINUT
PARAMETER	TEST CONDITIONS	Vcc	MIN TYP MAX	MIN TYP MAX	UNIT
	I _{OH} = -50 μA	2 V to 5.5 V	V _{CC} -0.1	V _{CC} -0.1	
Vou	$I_{OH} = -2 \text{ mA}$	2.3 V	2	2	v
VOH	I _{OH} = -8 mA	3 V	2.48	2.48	V
	I _{OH} = -16 mA	4.5 V	3.8	3.8	
	I _{OL} = 50 μA	2 V to 5.5 V	0.1	0.1	
Va	$I_{OL} = 2 \text{ mA}$	2.3 V	<i>/</i> 0.4	0.4	v
V _{OL}	$I_{OL} = 8 \text{ mA}$	3 V	<u></u> 0.44	0.44	V
	I _{OL} = 16 mA	4.5 V	0.55	0.55	
II	V _I = V _{CC} or GND	5.5 V	0.55 ±1	±1	μΑ
loz	V _O = V _{CC} or GND	5.5 V	±5	±5	μΑ
lcc	$V_I = V_{CC}$ or GND, $I_O = 0$	5.5 V	20	20	μΑ
l _{off}	$V_{ }$ or $V_{ }$ = 0 to 5.5 V	0 V	5	5	μΑ
Ci	V _I = V _{CC} or GND	3.3 V	1.9	1.9	pF

switching characteristics over recommended operating free-air temperature range, V_{CC} = 2.5 V \pm 0.2 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	Վ = 25° C	;	SN54L\	/541A	SN74L	/541A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	ONIT
^t pd*	Α	Υ			6.7	11.3	1	13,5	1	13.5	
t _{en} *	le I	Υ	C _L = 15 pF		8.5	16.6	1	19.5	1	19.5	ns
^t dis [*]	Œ	Υ	1		8.4	13.1	1	15	1	15	
^t pd	Α	Υ			8.7	15.9	1,	98	1	18.5	
^t en	Œ	Υ	0 50 5		10.5	20.7	. 1	24	1	24	
^t dis	Œ	Y	C _L = 50 pF		12.3	17.9	્રે 1	20	1	20	ns
t _{sk(o)} †						2	Q.			2	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

switching characteristics over recommended operating free-air temperature range, V_{CC} = 3.3 V \pm 0.3 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	T,	4 = 25°C	;	SN54L	/541A	SN74L	/541A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
^t pd*	Α	Υ			4.8	7	1	8.5	1	8.5	
^t en*	Œ	Υ	C _L = 15 pF		6.1	10.5	1	(1 1	1	11	ns
^t dis [*]	ŌĒ	Y			5.8	11	1	/ 12	1	12	
^t pd	Α	Y			6.1	10.5	1,%	12	1	12	
t _{en}	ŌE	Υ			7.4	14		16	1	16	
^t dis	le le	Υ	C _L = 50 pF		8.8	15.4	ূ 1	17.5	1	17.5	ns
t _{sk(o)} †						1.5	≪"			1.5	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

[†] Skew between any two outputs of the same package switching in the same direction



[†] Skew between any two outputs of the same package switching in the same direction

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switching characteristics over recommended operating free-air temperature range, V_{CC} = 5 V \pm 0.5 V (unless otherwise noted) (see Figure 1)

PARAMETER	FROM	то	LOAD	Т,	գ = 25° C	;	SN54L	V541A	SN74L	V541A	UNIT
PARAMETER	(INPUT)	(OUTPUT)	CAPACITANCE	MIN	TYP	MAX	MIN	MAX	MIN	MAX	UNIT
^t pd*	Α	Υ			3.5	5	1	6	1	6	
t _{en} *	o	Υ	C _L = 15 pF		4.3	7.2	1	8.5	1	8.5	ns
^t dis [*]	le	Υ			3.9	7	1	8	1	8	
^t pd	Α	Υ			4.3	7	1,4	W	1	8	
^t en	le	Υ	0 50-5		5.3	9.2	P	10.5	1	10.5	
^t dis	 	Y	$C_L = 50 pF$		5.6	8.8	€ 1	10	1	10	ns
t _{sk(o)} †						1	<			1	

^{*} On products compliant to MIL-PRF-38535, this parameter is not production tested.

noise characteristics, V_{CC} = 3.3 V, C_L = 50 pF, T_A = 25°C (see Note 5)

	PARAMETER				UNIT
	FARAMETER	MIN	MIN TYP MAX		
V _{OL(P)}	Quiet output, maximum dynamic V _{OL}		0.53	0.8	٧
V _{OL(V)}	Quiet output, minimum dynamic V _{OL}		-0.37	-0.8	٧
V _{OH(V)}	Quiet output, minimum dynamic V _{OH}		2.86		٧
V _{IH(D)}	High-level dynamic input voltage	2.31			٧
V _{IL(D)}	Low-level dynamic input voltage			0.99	٧

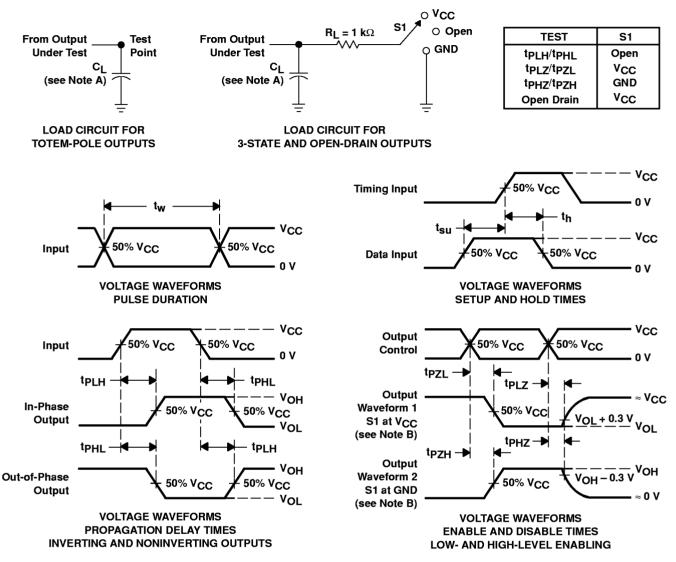
NOTE 5: Characteristics are for surface-mount packages only.

operating characteristics, T_A = 25°C

PARAMETER			TEST CO	ν _{CC}	TYP	UNIT	
<u> </u>	Dower dissination consistence	Outputs enabled	$C_1 = 50 pF$	f = 10 MHz	3.3 V	16.3	, E
Popd	Power dissipation capacitance	Outputs enabled	C _L = 50 p⊦,	I = 10 WITZ	5 V	17.8	p⊦

 $[\]ensuremath{^{\dagger}}$ Skew between any two outputs of the same package switching in the same direction

PARAMETER MEASUREMENT INFORMATION



- NOTES: A. C_L includes probe and jig capacitance.
 - B. Waveform 1 is for an output with internal conditions such that the output is low except when disabled by the output control. Waveform 2 is for an output with internal conditions such that the output is high except when disabled by the output control.
 - C. All input pulses are supplied by generators having the following characteristics: PRR \leq 1 MHz, $Z_{O} = 50 \Omega$, $t_{r} \leq$ 3 ns, $t_{f} \leq$ 3 ns.
 - D. The outputs are measured one at a time with one input transition per measurement.
 - E. tpLZ and tpHZ are the same as tdis.
 - F. tpzL and tpzH are the same as ten.
 - G. tpHL and tpLH are the same as tpd.

Figure 1. Load Circuit and Voltage Waveforms



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